

PMZB290UNE

20 V, single N-channel Trench MOSFET Rev. 3 — 23 March 2012

Product data sheet

1. **Product profile**

1.1 General description

N-channel enhancement mode Field-Effect Transistor (FET) in a leadless ultra small DFN1006B-3 (SOT883B) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

1.2 Features and benefits

- Very fast switching
- Low threshold voltage
- Trench MOSFET technology
- ESD protection up to 2 kV
- Ultra thin package profile of 0.37mm

1.3 Applications

- Relay driver
- High-speed line driver

- Low-side loadswitch
- Switching circuits

1.4 Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|------------------------|----------------------------------|---|------------|-----|-----|-----|------|
| V_{DS} | drain-source voltage | T _j = 25 °C | | - | - | 20 | V |
| V_{GS} | gate-source voltage | | | -8 | - | 8 | V |
| I _D | drain current | $V_{GS} = 4.5 \text{ V}; T_{amb} = 25 ^{\circ}\text{C}$ | <u>[1]</u> | - | - | 1 | Α |
| Static characteristics | | | | | | | |
| R _{DSon} | drain-source on-state resistance | $V_{GS} = 4.5 \text{ V}; I_D = 500 \text{ mA}; T_j = 25 \text{ °C}$ | | - | 290 | 380 | mΩ |

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².



2. Pinning information

Table 2. Pinning information

| Pin | Symbol | | Simplified outline | Graphic symbol |
|-----|--------|--------|-------------------------|----------------|
| 1 | G | gate | | |
| 2 | S | source | 1 3 | D |
| 3 | D | drain | 2 Transparent top view | G |
| | | | DFN1006B-3 (SOT883B) | S |
| | | | | 017aaa255 |

3. Ordering information

Table 3. Ordering information

| Type number | Package | | |
|-------------|------------|--|---------|
| | Name | Description | Version |
| PMZB290UNE | DFN1006B-3 | Leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.37 mm | SOT883B |

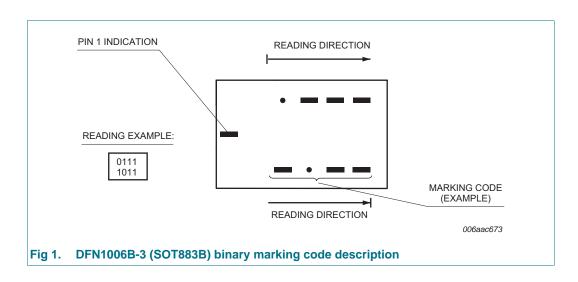
4. Marking

Table 4. Marking codes

| Type number | Marking code |
|-------------|--------------|
| PMZB290UNE | 0000 0110 |

[1] For DFN1006B-3 (SOT883B) binary marking code description see Figure 1.

4.1 Binary marking code description



PMZB290UNE

All information provided in this document is subject to legal disclaimers.

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|------------------|---------------------------------|--|------------|-----|------|------|
| V_{DS} | drain-source voltage | T _j = 25 °C | | - | 20 | V |
| V_{GS} | gate-source voltage | | | -8 | 8 | V |
| I _D | drain current | $V_{GS} = 4.5 \text{ V}; T_{amb} = 25 ^{\circ}\text{C}$ | <u>[1]</u> | - | 1 | Α |
| | | V _{GS} = 4.5 V; T _{amb} = 100 °C | <u>[1]</u> | - | 625 | mΑ |
| I _{DM} | peak drain current | T _{amb} = 25 °C; single pulse; t _p ≤ 10 μs | | - | 4 | Α |
| P _{tot} | total power dissipation | T _{amb} = 25 °C | [2] | - | 360 | mW |
| | | | <u>[1]</u> | - | 715 | mW |
| | | T _{sp} = 25 °C | | - | 2700 | mW |
| Tj | junction temperature | | | -55 | 150 | °C |
| T _{amb} | ambient temperature | | | -55 | 150 | °C |
| T _{stg} | storage temperature | | | -65 | 150 | °C |
| Source-drai | n diode | | | | | |
| Is | source current | T _{amb} = 25 °C | <u>[1]</u> | - | 680 | mΑ |
| ESD maxim | um rating | | | | | |
| V _{ESD} | electrostatic discharge voltage | НВМ | [3] | - | 2000 | V |

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².
- [2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.
- [3] Measured between all pins.

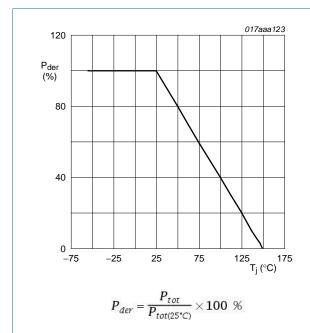
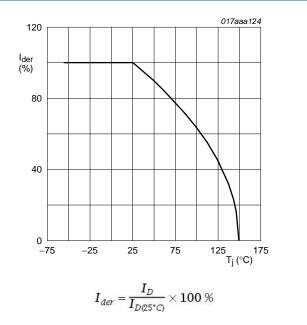
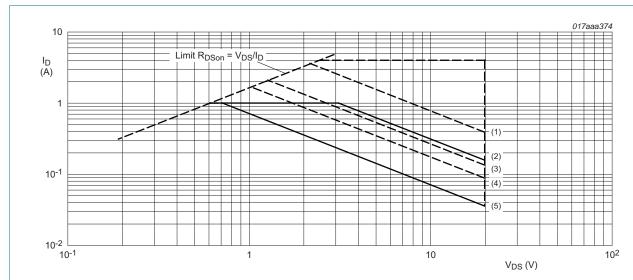


Fig 2. Normalized total power dissipation as a function of junction temperature



ig 3. Normalized continuous drain current as a function of junction temperature



I_{DM} = single pulse

- (1) $t_p = 1 \text{ ms}$
- (2) DC; $T_{sp} = 25 \, ^{\circ}\text{C}$
- (3) $t_p = 10 \text{ ms}$
- (4) $t_p = 100 \text{ ms}$
- (5) DC; $T_{amb} = 25 \, ^{\circ}C$; drain mounting pad 1 cm²

Fig 4. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drain-source voltage

6. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|-----------------------|--|-----------------|-----|-----|-----|-----|------|
| $R_{th(j-a)}$ | thermal resistance | in free air [1] | - | 305 | 360 | K/W | |
| | from junction to ambient | | [2] | - | 150 | 175 | K/W |
| R _{th(j-sp)} | thermal resistance from junction to solder point | | | - | - | 40 | K/W |

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².

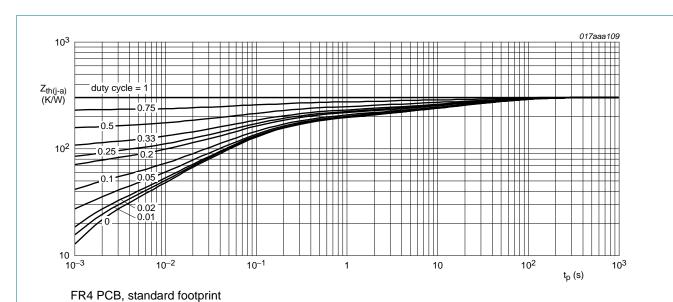


Fig 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

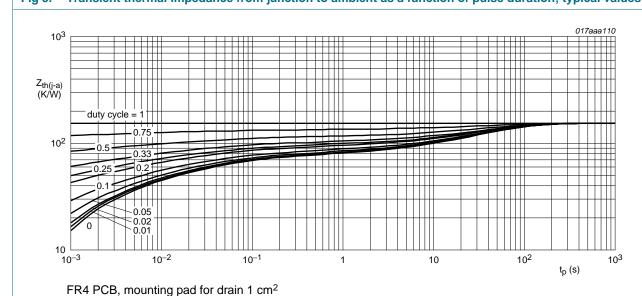


Fig 6. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

PMZB290UNE

All information provided in this document is subject to legal disclaimers.

5 of 15

7. Characteristics

Table 7. Characteristics

| Table 7. | Characteristics | | | | | |
|---------------------|-----------------------------------|---|------|------|------|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| Static cha | racteristics | | | | | |
| $V_{(BR)DSS}$ | drain-source breakdown voltage | $I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 °C$ | 20 | - | - | V |
| V_{GSth} | gate-source threshold voltage | $I_D = 250 \mu A; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$ | 0.5 | 0.75 | 0.95 | V |
| I _{DSS} | drain leakage current | $V_{DS} = 20 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$ | - | - | 1 | μΑ |
| | | $V_{DS} = 20 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 150 \text{ °C}$ | - | - | 10 | μΑ |
| I _{GSS} | gate leakage current | $V_{GS} = 8 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$ | - | - | 2 | μΑ |
| | | $V_{GS} = -8 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ °C}$ | - | - | 2 | μΑ |
| | | $V_{GS} = 4.5 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ °C}$ | - | - | 500 | nΑ |
| | | $V_{GS} = -4.5 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ °C}$ | - | - | 500 | nΑ |
| R _{DSon} | drain-source on-state resistance | $V_{GS} = 4.5 \text{ V}; I_D = 500 \text{ mA}; T_j = 25 \text{ °C}$ | - | 290 | 380 | mΩ |
| | | $V_{GS} = 4.5 \text{ V}; I_D = 500 \text{ mA}; T_j = 150 \text{ °C}$ | - | 460 | 610 | mΩ |
| | | $V_{GS} = 2.5 \text{ V}; I_D = 400 \text{ mA}; T_j = 25 \text{ °C}$ | - | 420 | 620 | mΩ |
| | | $V_{GS} = 1.8 \text{ V}; I_D = 100 \text{ mA}; T_j = 25 \text{ °C}$ | - | 600 | 1100 | mΩ |
| 9 _{fs} | forward transconductance | $V_{DS} = 10 \text{ V}; I_D = 200 \text{ mA}; T_j = 25 \text{ °C}$ | - | 1.6 | - | S |
| Dynamic | characteristics | | | | | |
| Q _{G(tot)} | total gate charge | $V_{DS} = 10 \text{ V}; I_D = 500 \text{ mA}; V_{GS} = 4.5 \text{ V};$ | - | 0.45 | 0.68 | nC |
| Q _{GS} | gate-source charge | T _j = 25 °C | - | 0.15 | - | nC |
| Q_{GD} | gate-drain charge | | - | 0.15 | - | nC |
| C _{iss} | input capacitance | $V_{DS} = 10 \text{ V}; f = 1 \text{ MHz}; V_{GS} = 0 \text{ V};$ | - | 55 | 83 | pF |
| Coss | output capacitance | $T_j = 25 ^{\circ}\text{C}$ | - | 15 | - | pF |
| C_{rss} | reverse transfer capacitance | | - | 7 | - | pF |
| t _{d(on)} | turn-on delay time | $V_{DS} = 10 \text{ V}; R_L = 250 \Omega; V_{GS} = 4.5 \text{ V};$ | - | 6 | 12 | ns |
| t _r | rise time | $R_{G(ext)} = 6 \Omega; T_j = 25 \text{ °C}$ | - | 4 | - | ns |
| t _{d(off)} | turn-off delay time | | - | 86 | 172 | ns |
| t _f | fall time | | - | 31 | - | ns |
| Source-di | rain diode | | | | | |
| V_{SD} | source-drain voltage | $I_S = 300 \text{ mA}; V_{GS} = 0 \text{ V}; T_i = 25 \text{ °C}$ | 0.48 | 0.77 | 1.2 | V |

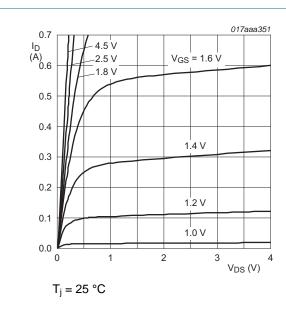
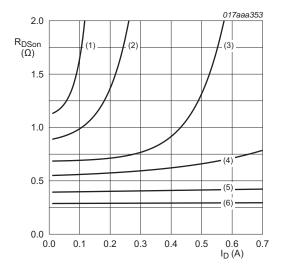


Fig 7. Output characteristics: drain current as a function of drain-source voltage; typical values



T_j = 25 °C

(1) $V_{GS} = 1.3 \text{ V}$

(2) $V_{GS} = 1.4 \text{ V}$

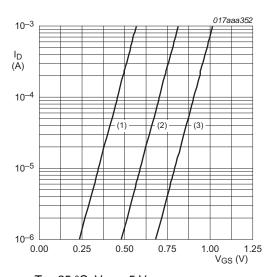
(3) $V_{GS} = 1.6 \text{ V}$

(4) $V_{GS} = 1.8 \text{ V}$

(5) $V_{GS} = 2.5 \text{ V}$

(6) $V_{GS} = 4.5 \text{ V}$

Fig 9. Drain-source on-state resistance as a function of drain current; typical values



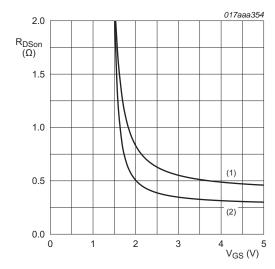
 $T_{j} = 25 \, ^{\circ}\text{C}; \, V_{DS} = 5 \, \text{V}$

(1) minimum values

(2) typical values

(3) maximum values

Fig 8. Sub-threshold drain current as a function of gate-source voltage

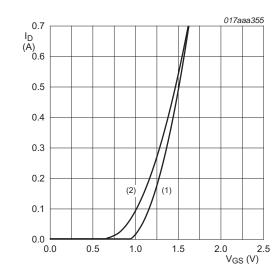


 $I_D = 400 \text{ mA}$

(1) $T_i = 150 \, ^{\circ}C$

(2) $T_j = 25 \, ^{\circ}\text{C}$

Fig 10. Drain-source on-state resistance as a function of gate-source voltage; typical values

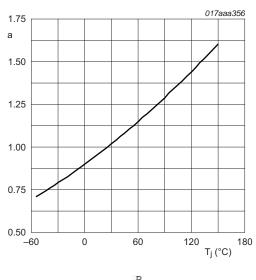


 $V_{DS} > I_D \times R_{DSon}$

(1)
$$T_i = 25 \, ^{\circ}C$$

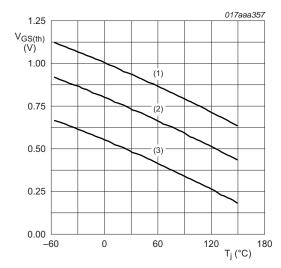
(2)
$$T_i = 150 \, ^{\circ}\text{C}$$

Fig 11. Transfer characteristics: drain current as a function of gate-source voltage; typical values



$$a = \frac{R_{DSon}}{R_{DSon(25^{\circ}C)}}$$

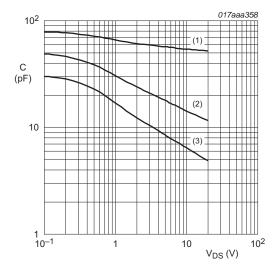
Fig 12. Normalized drain-source on-state resistance as a function of junction temperature; typical values



 $I_D = 0.25 \text{ mA}; V_{DS} = V_{GS}$

- (1) maximum values
- (2) typical values
- (3) minimum values

Fig 13. Gate-source threshold voltage as a function of junction temperature



 $f = 1 MHz; V_{GS} = 0 V$

- (1) C_{iss}
- (2) C_{oss}
- (3) C_{rss}

Fig 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

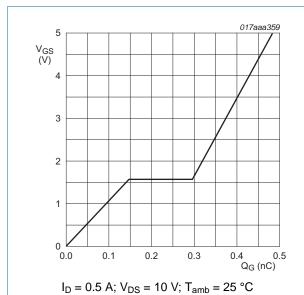


Fig 15. Gate-source voltage as a function of gate charge; typical values

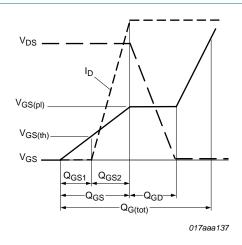
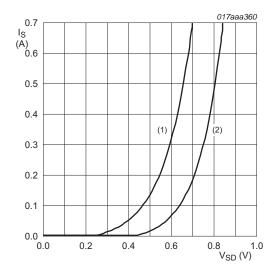


Fig 16. Gate charge waveform definitions



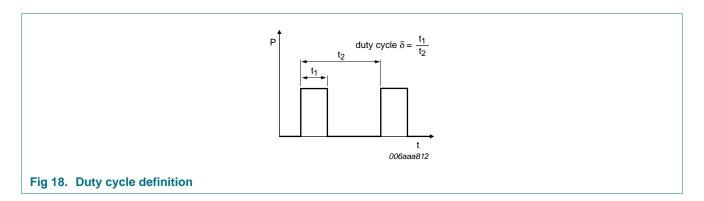
 $V_{GS} = 0 V$

(1) $T_j = 150 \, ^{\circ}C$

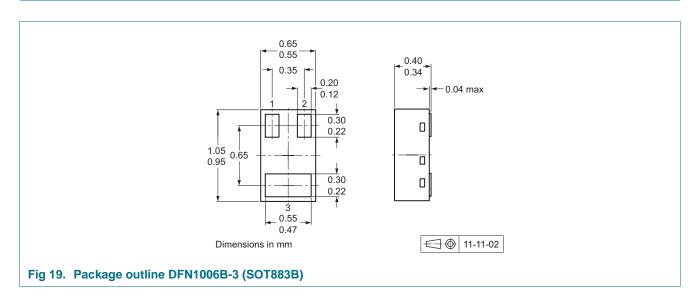
(2) $T_j = 25 \, ^{\circ}C$

Fig 17. Source current as a function of source-drain voltage; typical values

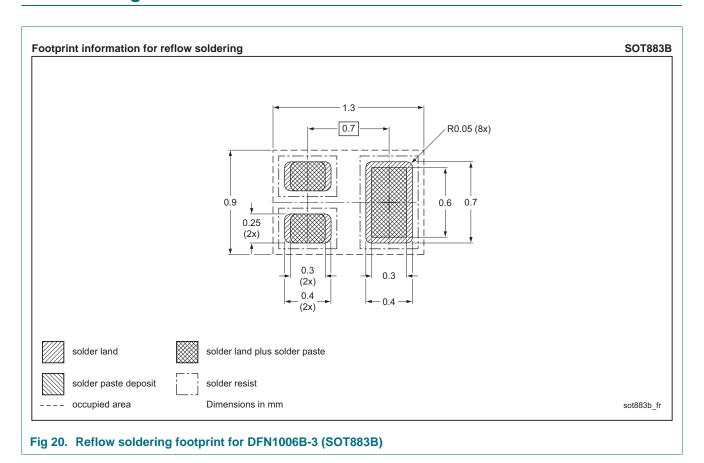
8. Test information



9. Package outline



10. Soldering



11. Revision history

Table 8. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|----------------|-----------------|--------------------------|---------------|----------------|
| PMZB290UNE v.3 | 20120323 | Product data sheet | - | PMZB290UNE v.2 |
| Modifications: | • 1.2 "Features | and benefits" corrected. | | |
| PMZB290UNE v.2 | 20120207 | Product data sheet | - | PMZB290UNE v.1 |
| PMZB290UNE v.1 | 20120201 | Product data sheet | - | - |

12. Legal information

12.1 Data sheet status

| Document status[1] [2] | Product status[3] | Definition |
|--------------------------------|-------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

- [1] Please consult the most recently issued document before initiating or completing a design
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

12.2 Definitions

Preview — The document is a preview version only. The document is still subject to formal approval, which may result in modifications or additions. Nexperia does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Nexperia and its customer, unless Nexperia and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Nexperia product is deemed to offer functions and qualities beyond those described in the Product data sheet

12.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Nexperia takes no responsibility for the content in this document if provided by an information source outside of Nexperia.

In no event shall Nexperia be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Nexperia's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of Nexperia.

Right to make changes — Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — Nexperia products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of a Nexperia product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Nexperia and its suppliers accept no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Nexperia products, and Nexperia accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Nexperia product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Nexperia does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Nexperia products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Nexperia does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

PMZB290UNE

All information provided in this document is subject to legal disclaimers.

© Nexperia B.V. 2017. All rights reserved

Terms and conditions of commercial sale — Nexperia products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nexperia.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective

agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Nexperia hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Nexperia products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Non-automotive qualified products — Unless this data sheet expressly states that this specific Nexperia product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. Nexperia accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without Nexperia's warranty of the

product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond Nexperia's specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies Nexperia for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond Nexperia's standard warranty and Nexperia's product specifications.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

12.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

13. Contact information

For more information, please visit:http://www.nexperia.com

For sales office addresses, please send an email to:salesaddresses@nexperia.com

Nexperia

PMZB290UNE

20 V, single N-channel Trench MOSFET

14. Contents

| 1 | Product profile | 1 |
|------|-------------------------|---|
| 1.1 | General description | 1 |
| 1.2 | Features and benefits | 1 |
| 1.3 | Applications | 1 |
| 1.4 | Quick reference data | 1 |
| 2 | Pinning information | 2 |
| 3 | Ordering information | 2 |
| 4 | Marking | 2 |
| 5 | Limiting values | 3 |
| 6 | Thermal characteristics | |
| 7 | Characteristics | 6 |
| 8 | Test information10 | 0 |
| 9 | Package outline | 0 |
| 10 | Soldering1 | 1 |
| 11 | Revision history12 | 2 |
| 12 | Legal information13 | 3 |
| 12.1 | Data sheet status | 3 |
| 12.2 | Definitions13 | 3 |
| 12.3 | Disclaimers | 3 |
| 12.4 | Trademarks14 | 4 |
| 13 | Contact information14 | 4 |
| | | |

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for MOSFET category:

Click to view products by Nexperia manufacturer:

Other Similar products are found below:

614233C 648584F IRFD120 JANTX2N5237 2N7000 FCA20N60_F109 FDZ595PZ 2SK2545(Q,T) 405094E 423220D

TPCC8103,L1Q(CM MIC4420CM-TR VN1206L 614234A 715780A NTNS3166NZT5G SSM6J414TU,LF(T 751625C

IPS70R2K0CEAKMA1 BUK954R8-60E DMN3404LQ-7 NTE6400 SQJ402EP-T1-GE3 2SK2614(TE16L1,Q) 2N7002KW-FAI

DMN1017UCP3-7 EFC2J004NUZTDG ECH8691-TL-W FCAB21350L1 P85W28HP2F-7071 DMN1053UCP4-7 NTE221 NTE2384

NTE2903 NTE2941 NTE2945 NTE2946 NTE2960 NTE2967 NTE2969 NTE2976 NTE455 NTE6400A NTE2910 NTE2916 NTE2956

NTE2911 US6M2GTR TK10A80W,S4X(S SSM6P69NU,LF